



STB5N62K3, STD5N62K3, STF5N62K3 STP5N62K3, STU5N62K3

N-channel 620 V, 1.28 Ω , 4.2 A SuperMESH3™ Power MOSFET
 D²PAK, DPAK, TO-220FP, TO-220 and IPAK

Features

| Order codes | V _{DSS} | R _{DS(on) max.} | I _D | P _w |
|------------------------|------------------|--------------------------|----------------|----------------|
| STB5N62K3 STD5N62K3 | 620 V | < 1.6 Ω | 4.2 A | 70 W |
| STF5N62K3 | | | | 25 W |
| STP5N62K3 STU5N62K3 | | | | 70 W |

- 100% avalanche tested
- Extremely large avalanche performance
- Gate charge minimized
- Very low intrinsic capacitance
- Improved diode reverse recovery characteristics
- Zener-protected

Application

Switching applications

Description

These devices are made using the SuperMESH3™ Power MOSFET technology that is obtained via improvements applied to STMicroelectronics' SuperMESH™ technology combined with a new optimized vertical structure. The resulting product has an extremely low on resistance, superior dynamic performance and high avalanche capability, making it especially suitable for the most demanding applications.

Table 1. Device summary

| Order codes | Marking | Packages | Packaging |
|---|---------|--|--|
| STB5N62K3 STD5N62K3 STF5N62K3 STP5N62K3 STU5N62K3 | 5N62K3 | D ² PAK DPAK TO-220FP TO-220 IPAK | Tape and reel Tape and reel Tube Tube Tube |

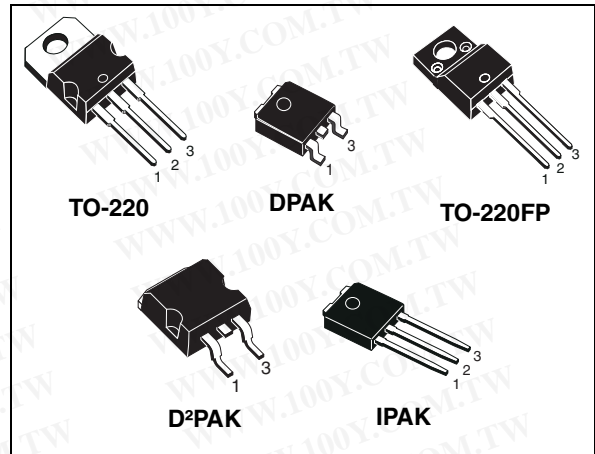
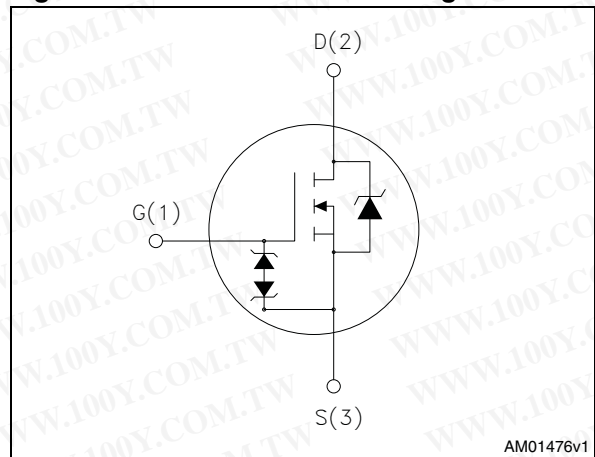


Figure 1. Internal schematic diagram



Contents

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1 Electrical ratings

Table 2. Absolute maximum ratings

| Symbol | Parameter | Value | | Unit |
|------------------------------------|--|--|---------------------|------|
| | | TO-220, DPAK D ² PAK, IPAK | TO-220FP | |
| V _{DS} | Drain- source voltage | 620 | | V |
| V _{GS} | Gate- source voltage | ± 30 | | V |
| I _D | Drain current (continuous) at T _C = 25 °C | 4.2 | 4.2 ⁽¹⁾ | A |
| I _D | Drain current (continuous) at T _C = 100 °C | 3 | 3 ⁽¹⁾ | A |
| I _{DM} ⁽²⁾ | Drain current (pulsed) | 16.8 | 16.8 ⁽¹⁾ | A |
| P _{TOT} | Total dissipation at T _C = 25 °C | 70 | 25 | W |
| I _{AR} | Avalanche current, repetitive or not-repetitive (pulse width limited by T _J max) | 4.2 | | A |
| E _{AS} | Single pulse avalanche energy (starting T _J = 25 °C, I _D = I _{AR} , V _{DD} = 50 V) | 120 | | mJ |
| dv/dt ⁽³⁾ | Peak diode recovery voltage slope | 12 | | V/ns |
| di/dt ⁽³⁾ | Diode reverse recovery current slope | 400 | | A/μs |
| V _{ISO} | Insulation withstand voltage (AC) | | 2500 | |
| T _J T _{stg} | Operating junction temperature Storage temperature | - 55 to 150 | | °C |

- Limited only by maximum temperature allowed
- Pulse width limited by safe operating area
- I_{SD} ≤ I_D, peak V_{DS} ≤ V_{(BR)DSS}, V_{DD} = 80% V_{(BR)DSS}

Table 3. Thermal data

| Symbol | Parameter | Value | | | | | Unit |
|-----------------------|--|--------|--------------------|------|----------|------|------|
| | | TO-220 | D ² PAK | IPAK | TO-220FP | DPAK | |
| R _{thj-case} | Thermal resistance junction-case max | 1.79 | | | 5 | 1.79 | °C/W |
| R _{thj-amb} | Thermal resistance junction-amb max | 62.50 | | | 62.50 | | °C/W |
| R _{thj-pcb} | Thermal resistance junction-pcb max | | 30 | | | 50 | °C/W |
| T _J | Maximum lead temperature for soldering purpose | 300 | | | 300 | | °C/W |

2 Electrical characteristics

(T_{case} =25 °C unless otherwise specified)

Table 4. On /off states

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|----------------------|---|--|------|------|---------|----------|
| V _{(BR)DSS} | Drain-source breakdown voltage | I _D = 1 mA, V _{GS} = 0 | 620 | | | V |
| I _{DSS} | Zero gate voltage drain current (V _{GS} = 0) | V _{DS} = Max rating V _{DS} = Max rating, T _C =125 °C | | | 1 50 | μA μA |
| I _{GSS} | Gate-body leakage current (V _{DS} = 0) | V _{GS} = ± 20 V; V _{DS} =0 | | | ±10 | μA |
| V _{GS(th)} | Gate threshold voltage | V _{DS} = V _{GS} , I _D = 50 μA | 3 | 3.75 | 4.5 | V |
| R _{DS(on)} | Static drain-source on resistance | V _{GS} = 10 V, I _D = 2.1 A | | 1.28 | 1.6 | Ω |

Table 5. Dynamic

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|------------------------------------|-------------------------------|--|------|------|------|------|
| C _{iss} | Input capacitance | V _{DS} = 50 V, f = 1 MHz, V _{GS} = 0 | - | 680 | - | pF |
| C _{oss} | Output capacitance | | | 50 | | pF |
| C _{rss} | Reverse transfer capacitance | | | 8 | | pF |
| C _{OSS eq} ⁽¹⁾ | Equivalent output capacitance | V _{GS} = 0, V _{DS} = 0 to 496 V | | 16.6 | | pF |
| R _g | Gate input resistance | f=1 MHz open drain | - | 4 | - | Ω |
| Q _g | Total gate charge | V _{DD} = 496 V, I _D = 4.2 A, V _{GS} = 10 V <i>(see Figure 20)</i> | - | 26 | - | nC |
| Q _{gs} | Gate-source charge | | | 4 | | nC |
| Q _{gd} | Gate-drain charge | | | 16 | | nC |

1. C_{OSS eq} is defined as a constant equivalent capacitance giving the same charging time as C_{OSS} when V_{DS} increases from 0 to 80% V_{DSS}

Table 6. Switching times

| Symbol | Parameter | Test conditions | Min. | Typ. | Max | Unit |
|--------------|---------------------|---|------|------|-----|------|
| $t_{d(on)}$ | Turn-on delay time | $V_{DD} = 310 \text{ V}$, $I_D = 4.2 \text{ A}$, $R_G = 4.7 \Omega$, $V_{GS} = 10 \text{ V}$ (see Figure 19) | - | 12 | - | ns |
| t_r | Rise time | | - | 8 | - | ns |
| $t_{d(off)}$ | Turn-off-delay time | | - | 40 | - | ns |
| t_f | Fall time | | - | 21 | - | ns |

Table 7. Source drain diode

| Symbol | Parameter | Test conditions | Min. | Typ. | Max | Unit |
|-----------------|-------------------------------|---|------|------|------|------|
| I_{SD} | Source-drain current | | - | | 4.2 | A |
| $I_{SDM}^{(1)}$ | Source-drain current (pulsed) | | | | 16.8 | A |
| $V_{SD}^{(2)}$ | Forward on voltage | $I_{SD} = 4.2 \text{ A}$, $V_{GS} = 0$ | - | | 1.5 | V |
| t_{rr} | Reverse recovery time | $I_{SD} = 4.2 \text{ A}$, $di/dt = 100 \text{ A}/\mu\text{s}$ $V_{DD} = 60 \text{ V}$ (see Figure 21) | - | 290 | | ns |
| Q_{rr} | Reverse recovery charge | | - | 1900 | | nC |
| I_{RRM} | Reverse recovery current | | - | 13 | | A |
| t_{rr} | Reverse recovery time | $I_{SD} = 4.2 \text{ A}$, $di/dt = 100 \text{ A}/\mu\text{s}$ $V_{DD} = 60 \text{ V}$, $T_J = 150 \text{ }^\circ\text{C}$ (see Figure 21) | - | 320 | | ns |
| Q_{rr} | Reverse recovery charge | | - | 2200 | | nC |
| I_{RRM} | Reverse recovery current | | - | 14 | | A |

1. Pulse width limited by safe operating area

2. Pulsed: pulse duration = 300 μs , duty cycle 1.5%

Table 8. Gate-source Zener diode

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|------------|-------------------------------|--|------|------|------|------|
| BV_{GSO} | Gate-source breakdown voltage | $I_{gs} = \pm 1 \text{ mA}$ (open drain) | 30 | - | - | V |

The built-in back-to-back Zener diodes have specifically been designed to enhance not only the device's ESD capability, but also to make them safely absorb possible voltage transients that may occasionally be applied from gate to source. In this respect the Zener voltage is appropriate to achieve an efficient and cost-effective intervention to protect the device's integrity. These integrated Zener diodes thus avoid the usage of external components.

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area for D²PAK, TO-220

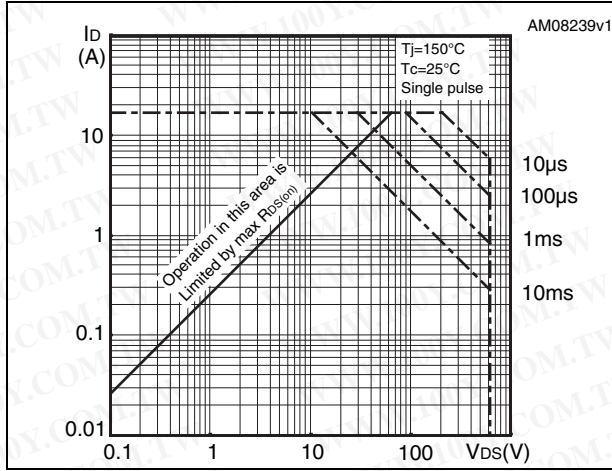


Figure 3. Thermal impedance for D²PAK, TO-220

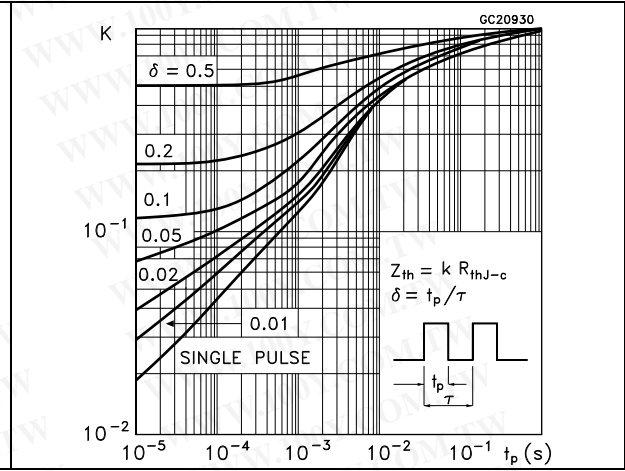


Figure 4. Safe operating area for TO-220FP

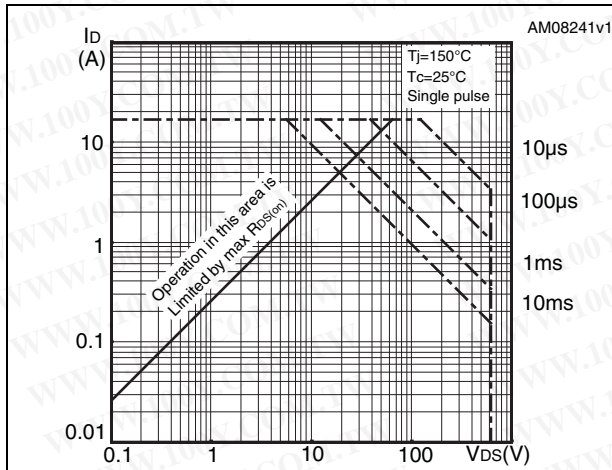


Figure 5. Thermal impedance for TO-220FP

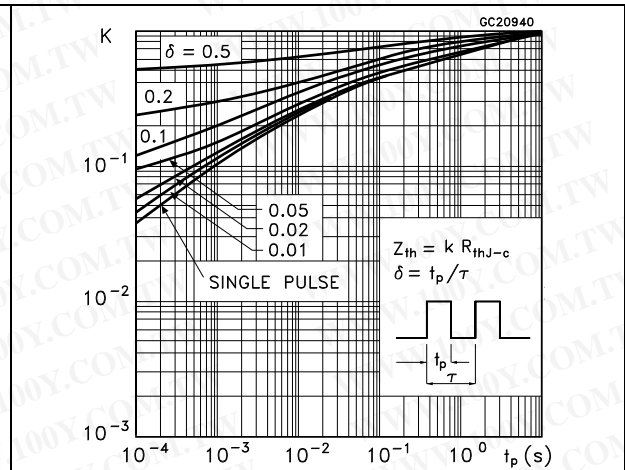


Figure 6. Safe operating area for DPAK, IPAK

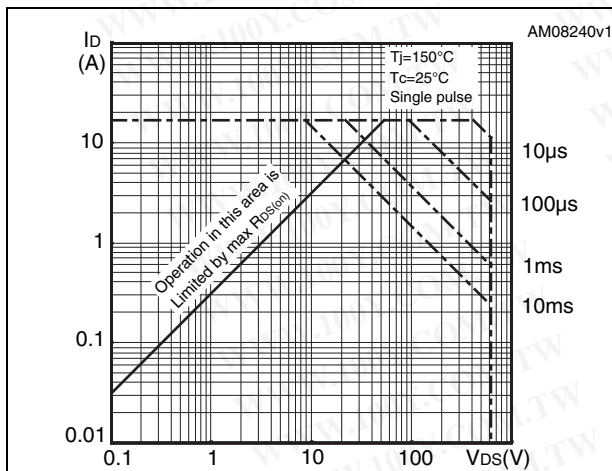


Figure 7. Thermal impedance for DPAK, IPAK

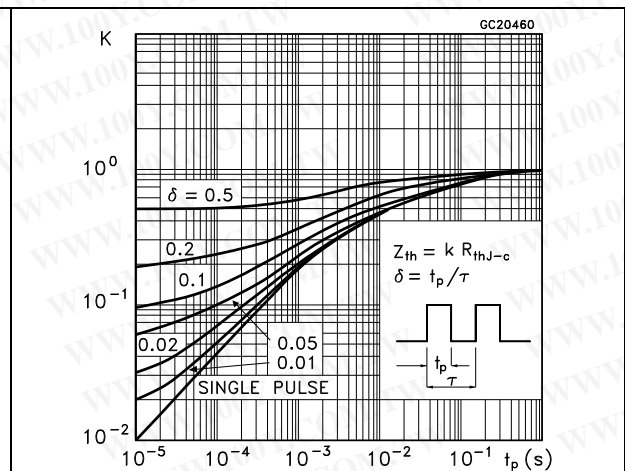


Figure 8. Output characteristics

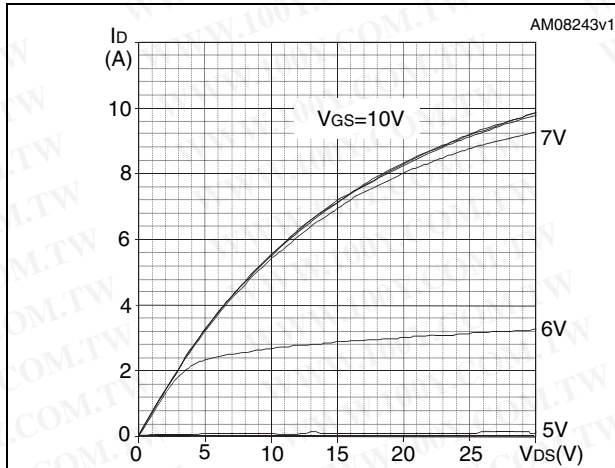


Figure 9. Transfer characteristics

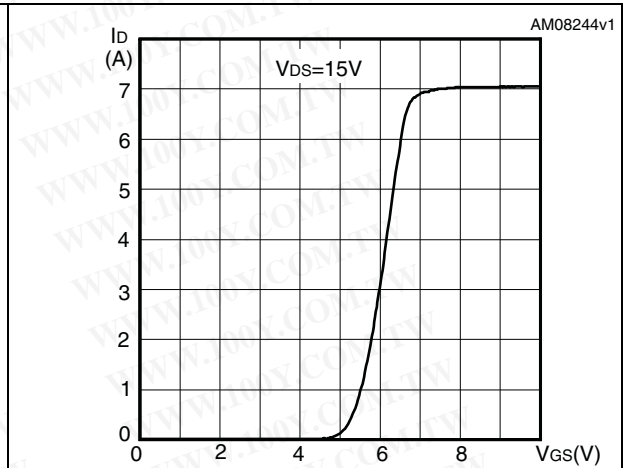


Figure 10. Gate charge vs gate-source voltage

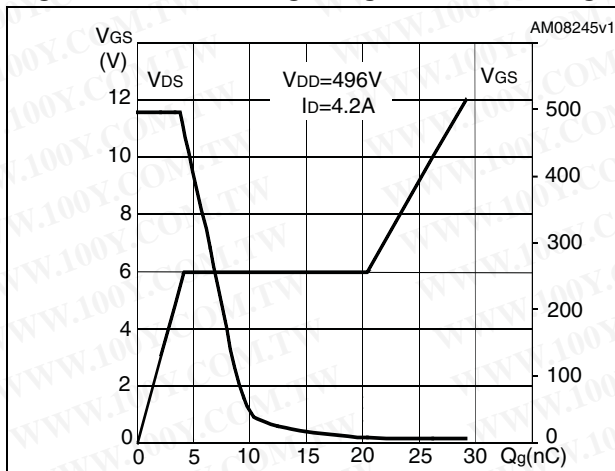


Figure 11. Static drain-source on resistance

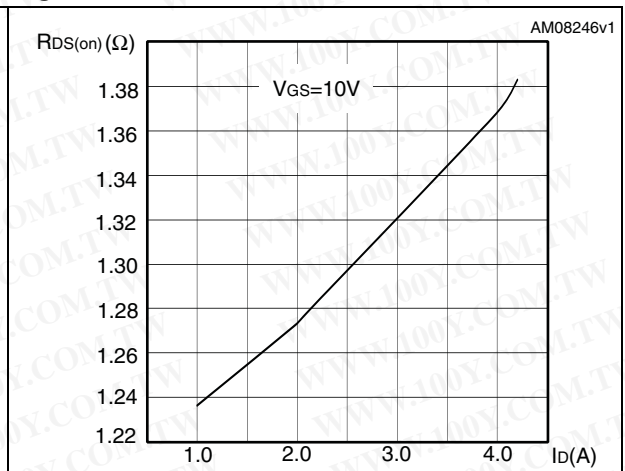


Figure 12. Capacitance variations

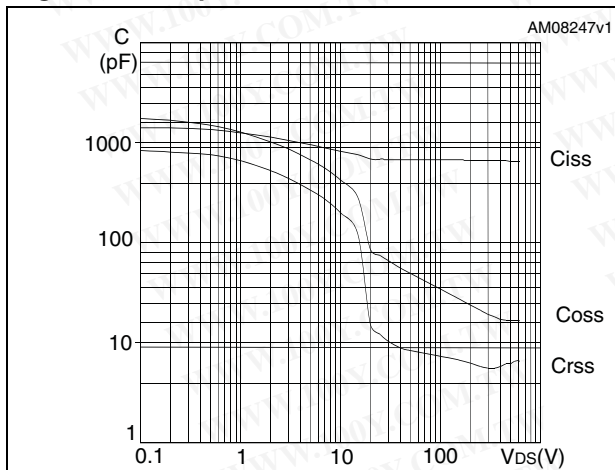


Figure 13. Output capacitance stored energy

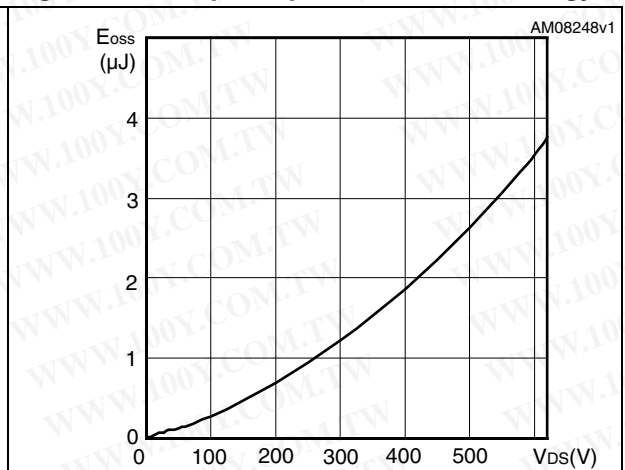


Figure 14. Normalized gate threshold voltage vs temperature

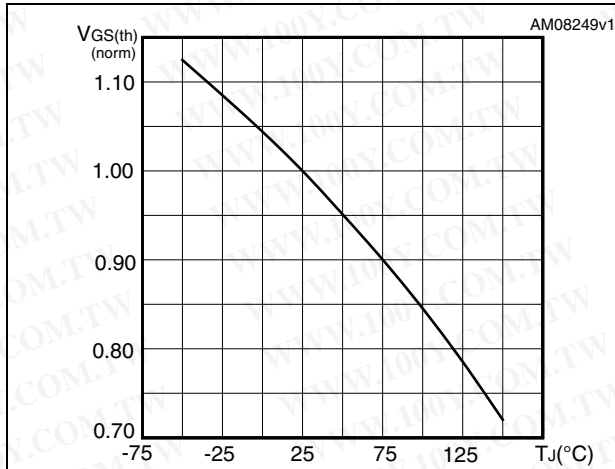


Figure 15. Normalized on resistance vs temperature

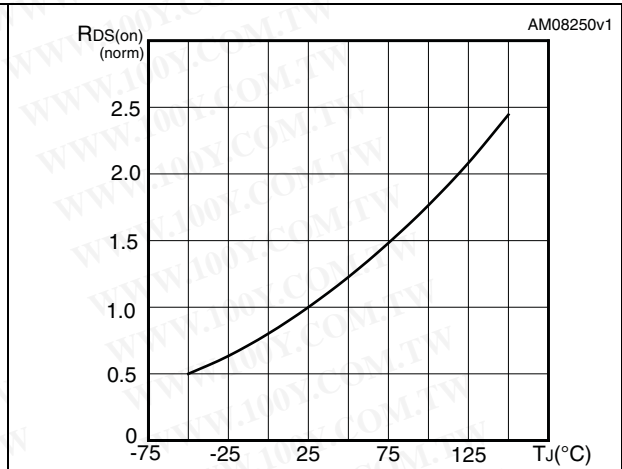


Figure 16. Source-drain diode forward characteristics

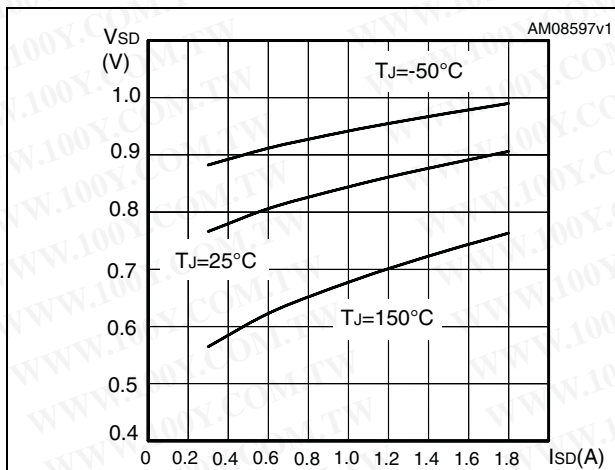


Figure 17. Normalized BV_{DSS} vs temperature

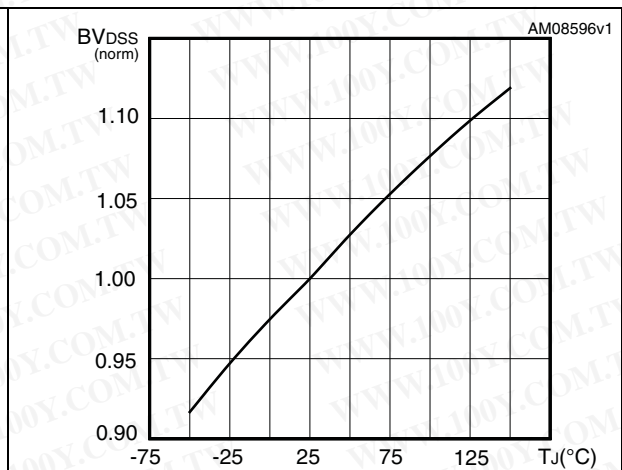
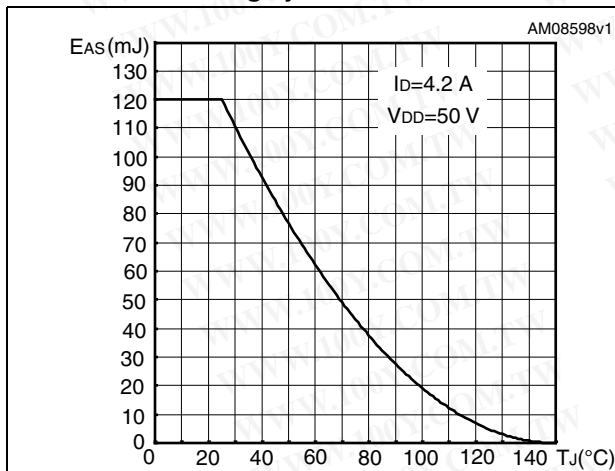


Figure 18. Maximum avalanche energy vs starting Tj



3 Test circuits

Figure 19. Switching times test circuit for resistive load

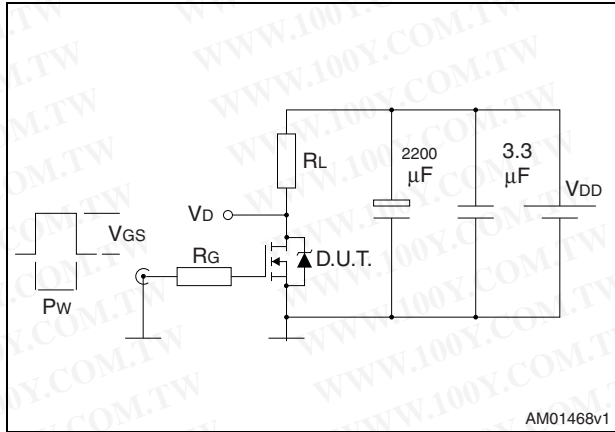


Figure 20. Gate charge test circuit

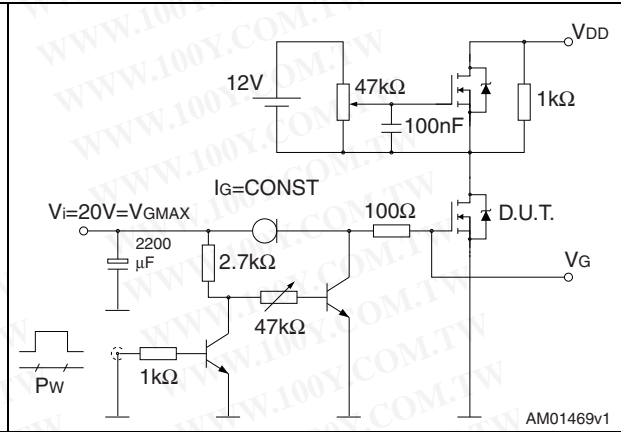


Figure 21. Test circuit for inductive load switching and diode recovery times

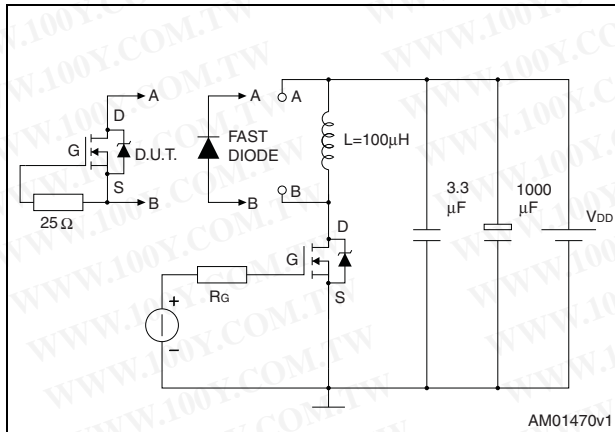


Figure 22. Unclamped inductive load test circuit

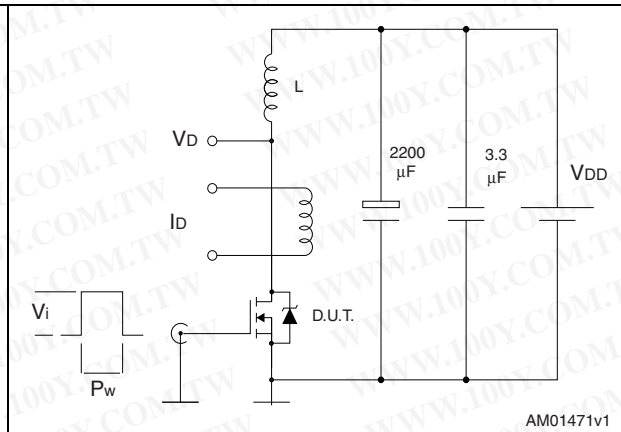


Figure 23. Unclamped inductive waveform

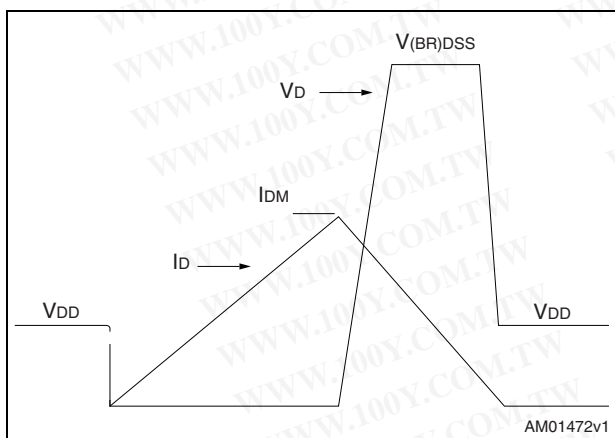
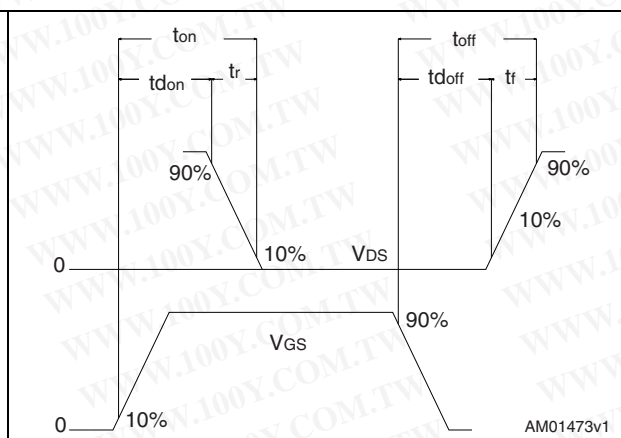


Figure 24. Switching time waveform



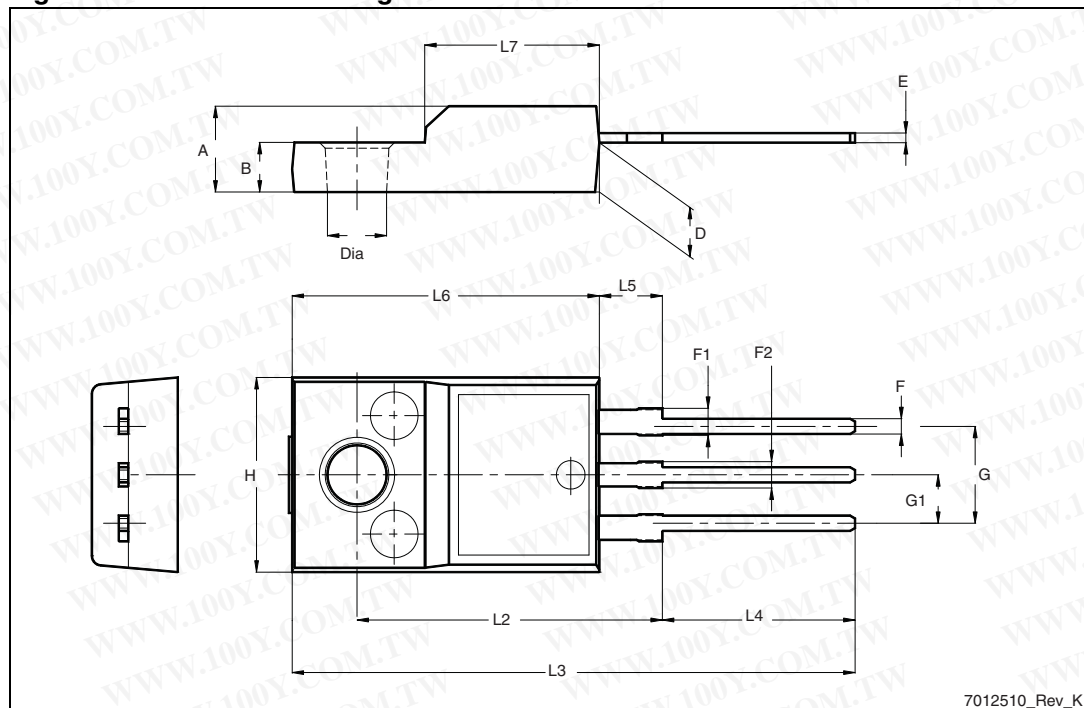
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Table 9. TO-220FP mechanical data

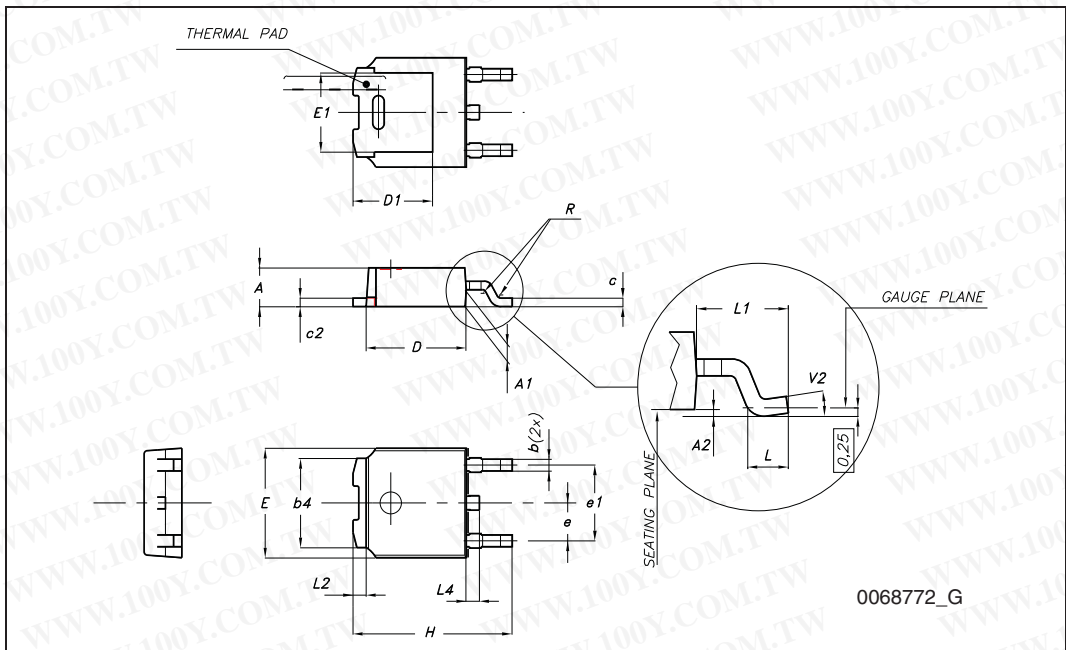
| Dim. | mm | | |
|------|------|------|------|
| | Min. | Typ. | Max. |
| A | 4.4 | | 4.6 |
| B | 2.5 | | 2.7 |
| D | 2.5 | | 2.75 |
| E | 0.45 | | 0.7 |
| F | 0.75 | | 1 |
| F1 | 1.15 | | 1.70 |
| F2 | 1.15 | | 1.70 |
| G | 4.95 | | 5.2 |
| G1 | 2.4 | | 2.7 |
| H | 10 | | 10.4 |
| L2 | | 16 | |
| L3 | 28.6 | | 30.6 |
| L4 | 9.8 | | 10.6 |
| L5 | 2.9 | | 3.6 |
| L6 | 15.9 | | 16.4 |
| L7 | 9 | | 9.3 |
| Dia | 3 | | 3.2 |

Figure 25. TO-220FP drawing



TO-252 (DPAK) mechanical data

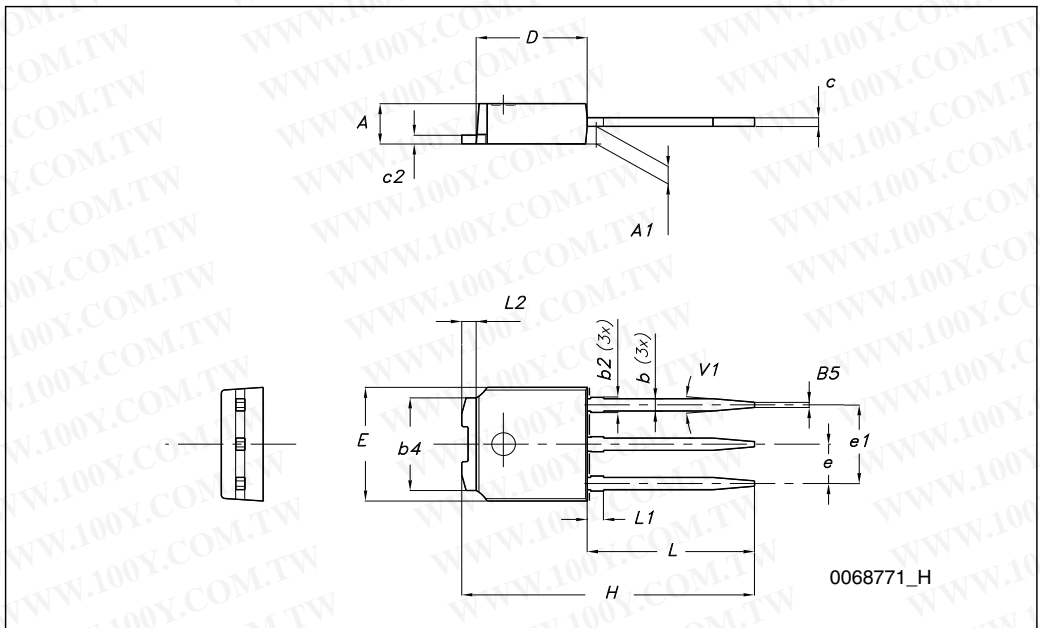
| DIM. | mm. | | |
|------|------|------|-------|
| | min. | typ | max. |
| A | 2.20 | | 2.40 |
| A1 | 0.90 | | 1.10 |
| A2 | 0.03 | | 0.23 |
| b | 0.64 | | 0.90 |
| b4 | 5.20 | | 5.40 |
| c | 0.45 | | 0.60 |
| c2 | 0.48 | | 0.60 |
| D | 6.00 | | 6.20 |
| D1 | | 5.10 | |
| E | 6.40 | | 6.60 |
| E1 | | 4.70 | |
| e | | 2.28 | |
| e1 | 4.40 | | 4.60 |
| H | 9.35 | | 10.10 |
| L | 1 | | |
| L1 | | 2.80 | |
| L2 | | 0.80 | |
| L4 | 0.60 | | 1 |
| R | | 0.20 | |
| V2 | 0° | | 8° |



0068772_G

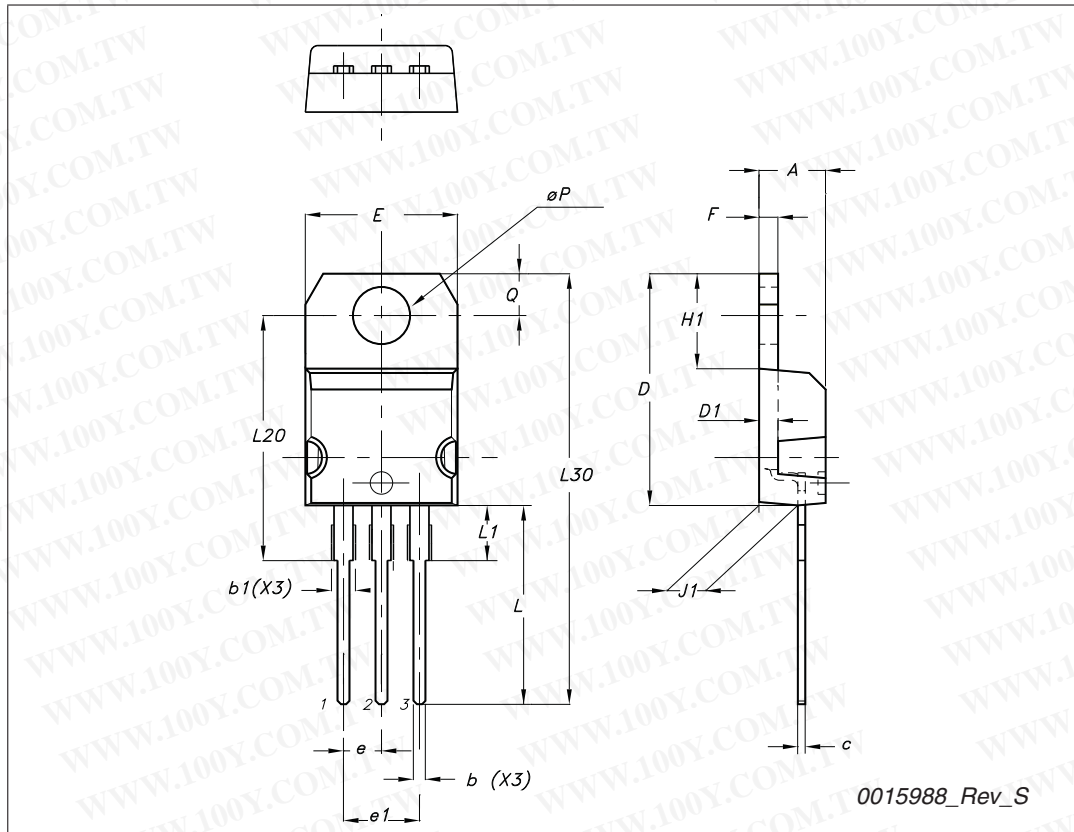
TO-251 (IPAK) mechanical data

| DIM. | mm. | | |
|------|------|-------|------|
| | min. | typ | max. |
| A | 2.20 | | 2.40 |
| A1 | 0.90 | | 1.10 |
| b | 0.64 | | 0.90 |
| b2 | | | 0.95 |
| b4 | 5.20 | | 5.40 |
| c | 0.45 | | 0.60 |
| c2 | 0.48 | | 0.60 |
| D | 6.00 | | 6.20 |
| E | 6.40 | | 6.60 |
| e | | 2.28 | |
| e1 | 4.40 | | 4.60 |
| H | | 16.10 | |
| L | 9.00 | | 9.40 |
| (L1) | 0.80 | | 1.20 |
| L2 | | 0.80 | |
| V1 | | 10° | |



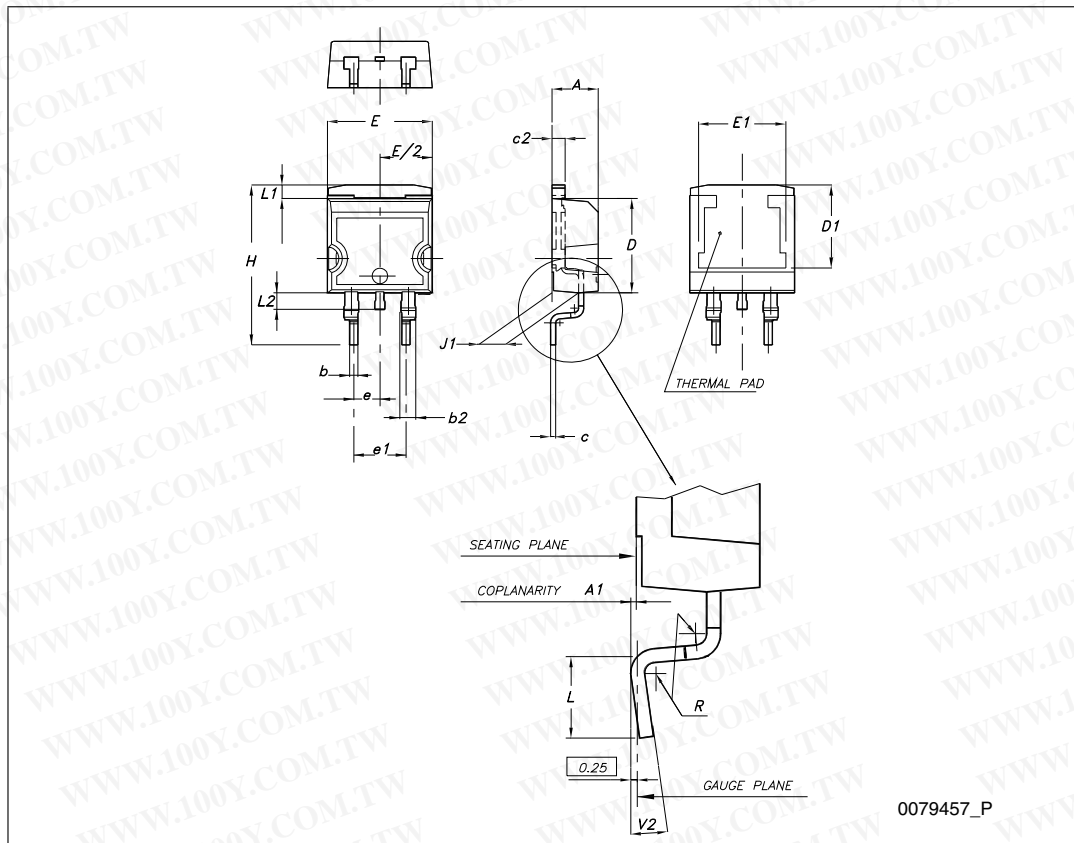
TO-220 type A mechanical data

| Dim | mm | | |
|-----|-------|-------|-------|
| | Min | Typ | Max |
| A | 4.40 | | 4.60 |
| b | 0.61 | | 0.88 |
| b1 | 1.14 | | 1.70 |
| c | 0.48 | | 0.70 |
| D | 15.25 | | 15.75 |
| D1 | | 1.27 | |
| E | 10 | | 10.40 |
| e | 2.40 | | 2.70 |
| e1 | 4.95 | | 5.15 |
| F | 1.23 | | 1.32 |
| H1 | 6.20 | | 6.60 |
| J1 | 2.40 | | 2.72 |
| L | 13 | | 14 |
| L1 | 3.50 | | 3.93 |
| L20 | | 16.40 | |
| L30 | | 28.90 | |
| ∅P | 3.75 | | 3.85 |
| Q | 2.65 | | 2.95 |



D²PAK (TO-263) mechanical data

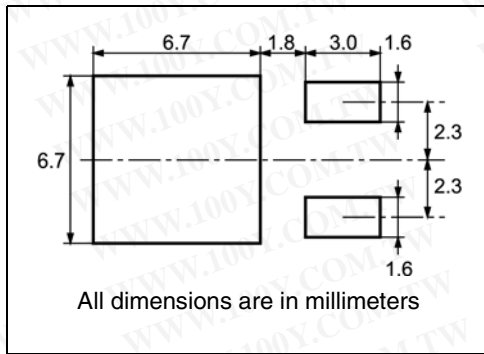
| Dim. | mm. | | |
|------|------|------|-------|
| | Min. | Typ. | Max. |
| A | 4.40 | | 4.60 |
| A1 | 0.03 | | 0.23 |
| b | 0.70 | | 0.93 |
| b2 | 1.14 | | 1.70 |
| c | 0.45 | | 0.60 |
| c2 | 1.23 | | 1.36 |
| D | 8.95 | | 9.35 |
| D1 | 7.50 | | |
| E | 10 | | 10.40 |
| E1 | 8.50 | | |
| e | | 2.54 | |
| e1 | 4.88 | | 5.28 |
| H | 15 | | 15.85 |
| J1 | 2.49 | | 2.69 |
| L | 2.29 | | 2.79 |
| L1 | 1.27 | | 1.40 |
| L2 | 1.30 | | 1.75 |
| R | | 0.4 | |
| V2 | 0° | | 8° |



0079457_P

5 Package mechanical data

DPAK FOOTPRINT



TAPE AND REEL SHIPMENT

40 mm min. Access hole at slot location

Full radius

Tape slot in core for tape start 2.5mm min. width

G measured at hub

REEL MECHANICAL DATA

| DIM. | mm | | inch | |
|------|------|------|-------|--------|
| | MIN. | MAX. | MIN. | MAX. |
| A | | 330 | | 12.992 |
| B | 1.5 | | 0.059 | |
| C | 12.8 | 13.2 | 0.504 | 0.520 |
| D | 20.2 | | 0.795 | |
| G | 16.4 | 18.4 | 0.645 | 0.724 |
| N | 50 | | 1.968 | |
| T | | 22.4 | | 0.881 |

TAPE MECHANICAL DATA

| DIM. | mm | | inch | |
|------|------|------|-------|-------|
| | MIN. | MAX. | MIN. | MAX. |
| A0 | 6.8 | 7 | 0.267 | 0.275 |
| B0 | 10.4 | 10.6 | 0.409 | 0.417 |
| B1 | | 12.1 | | 0.476 |
| D | 1.5 | 1.6 | 0.059 | 0.063 |
| D1 | 1.5 | | 0.059 | |
| E | 1.65 | 1.85 | 0.065 | 0.073 |
| F | 7.4 | 7.6 | 0.291 | 0.299 |
| K0 | 2.55 | 2.75 | 0.100 | 0.108 |
| P0 | 3.9 | 4.1 | 0.153 | 0.161 |
| P1 | 7.9 | 8.1 | 0.311 | 0.319 |
| P2 | 1.9 | 2.1 | 0.075 | 0.082 |
| R | 40 | | 1.574 | |
| W | 15.7 | 16.3 | 0.618 | 0.641 |

10 pitches cumulative tolerance on tape +/- 0.2 mm

TOP COVER TAPE

Center line of cavity

User Direction of Feed

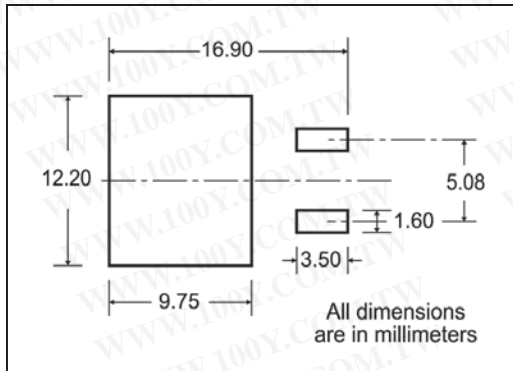
TRL

FEED DIRECTION

Bending radius R min.

For machine ref. only including draft and radii concentric around B0

D²PAK FOOTPRINT



TAPE AND REEL SHIPMENT

40 mm min. Access hole at slot location

Full radius

Tape slot in core for tape start 2.5mm min. width

G measured at hub

REEL MECHANICAL DATA

| DIM. | mm | | inch | |
|------|------|------|-------|--------|
| | MIN. | MAX. | MIN. | MAX. |
| A | | 330 | | 12.992 |
| B | 1.5 | | 0.059 | |
| C | 12.8 | 13.2 | 0.504 | 0.520 |
| D | 20.2 | | 0.795 | |
| G | 24.4 | 26.4 | 0.960 | 1.039 |
| N | 100 | | 3.937 | |
| T | | 30.4 | | 1.197 |

| BASE QTY | BULK QTY |
|----------|----------|
| 1000 | 1000 |

TAPE MECHANICAL DATA

| DIM. | mm | | inch | |
|------|------|------|--------|--------|
| | MIN. | MAX. | MIN. | MAX. |
| A0 | 10.5 | 10.7 | 0.413 | 0.421 |
| B0 | 15.7 | 15.9 | 0.618 | 0.626 |
| D | 1.5 | 1.6 | 0.059 | 0.063 |
| D1 | 1.59 | 1.61 | 0.062 | 0.063 |
| E | 1.65 | 1.85 | 0.065 | 0.073 |
| F | 11.4 | 11.6 | 0.449 | 0.456 |
| K0 | 4.8 | 5.0 | 0.189 | 0.197 |
| P0 | 3.9 | 4.1 | 0.153 | 0.161 |
| P1 | 11.9 | 12.1 | 0.468 | 0.476 |
| P2 | 1.9 | 2.1 | 0.075 | 0.082 |
| R | 50 | | 1.574 | |
| T | 0.25 | 0.35 | 0.0098 | 0.0137 |
| W | 23.7 | 24.3 | 0.933 | 0.956 |

TOP COVER TAPE

10 pitches cumulative tolerance on tape +/- 0.2 mm

User Direction of Feed

Center line of cavity

TRL

FEED DIRECTION

Bending radius R min.

6 Revision history

Table 10. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 09-Apr-2010 | 1 | First release. |
| 20-Oct-2010 | 2 | <ul style="list-style-type: none">– Added new package, mechanical data: IPAK;– Added new package, mechanical data: D²PAK;– Document status promoted from preliminary data to datasheet. |

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